Solid Tantalum Surface Mount Capacitors **TANTAMOUNT[™] Molded Case, HI-TMP[®]** High Temperature 150 °C, Automotive Grade



www.vishay.com

PERFORMANCE / ELECTRICAL CHARACTERISTICS

www.vishav.com/doc?40215

Operating Temperature: -55 °C to +150 °C Capacitance Range: 0.33 µF to 220 µF Capacitance Tolerance: ± 10 %, ± 20 % Voltage Rating: 6.3 V_{DC} to 50 V_{DC}

FEATURES

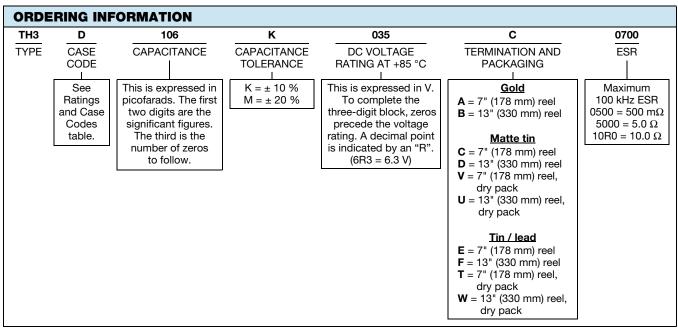
- Operating temperature up to 150 °C with 50 % voltage derating
- AEC-Q200 gualified
- 100 % surge current tested (B, C, D, E case sizes)
- RoHS-compliant terminations available: matte tin (all cases), gold (A, C, D, and E cases)
- Standard EIA 535BAAC case size (A through E)
- Compliant terminations
- Moisture sensitivity level 1
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Note

This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

APPLICATIONS

- Automotive
- Industrial
- High temperature sensors



Notes

- We reserve the right to supply higher voltage ratings and tighter capacitance tolerance capacitors in the same case size. Voltage substitutions will be marked with the higher voltage rating
- Dry pack as specified in J-STD-033 for MSL3. Applicable for D and E cases only

ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000







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DIMENSIONS in inches [millimeters]

$T_{H} (MIN.) \qquad \qquad$								
CASE CODE	EIA SIZE	L	w	н	Р	Tw	T _H (MIN.)	
А	3216-18	0.126 ± 0.008 [3.2 ± 0.20]	0.063 ± 0.008 [1.6 ± 0.20]	0.063 ± 0.008 [1.6 ± 0.20]	$\begin{array}{c} 0.031 \pm 0.012 \\ [0.80 \pm 0.30] \end{array}$	0.047 ± 0.004 [1.2 ± 0.10]	0.028 [0.70]	
В	3528-21	0.138 ± 0.008 [3.5 ± 0.20]	0.110 ± 0.008 [2.8 ± 0.20]	0.075 ± 0.008 [1.9 ± 0.20]	$\begin{array}{c} 0.031 \pm 0.012 \\ [0.80 \pm 0.30] \end{array}$	0.087 ± 0.004 [2.2 ± 0.10]	0.028 [0.70]	
С	6032-28	$\begin{array}{c} 0.236 \pm 0.012 \\ [6.0 \pm 0.30] \end{array}$	0.126 ± 0.012 [3.2 ± 0.30]	0.098 ± 0.012 [2.5 ± 0.30]	0.051 ± 0.012 [1.3 ± 0.30]	0.087 ± 0.004 [2.2 ± 0.10]	0.039 [1.0]	
D	7343-31	0.287 ± 0.012 [7.3 ± 0.30]	0.169 ± 0.012 [4.3 ± 0.30]	0.110 ± 0.012 [2.8 ± 0.30]	0.051 ± 0.012 [1.3 ± 0.30]	0.094 ± 0.004 [2.4 ± 0.10]	0.039 [1.0]	
E	7343-43	0.287 ± 0.012 [7.3 ± 0.30]	0.169 ± 0.012 [4.3 ± 0.30]	0.157 ± 0.012 [4.0 ± 0.30]	0.051 ± 0.012 [1.3 ± 0.30]	0.094 ± 0.004 [2.4 ± 0.10]	0.039 [1.0]	

Note

• Glue pad (non-conductive, part of molded case) is dedicated for glue attachment (as user option)

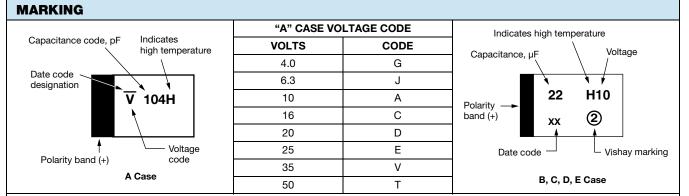
μF	6.3 V	10 V	16 V	20 V	25 V	35 V	50 V
0.33						A (11.0)	
0.47					A (14.0)		
0.68							
1.0			A (6.5)	A (5.9)	A (3.0, 5.2) / B (5.0)	A (6.6) / B (4.4)	C (3.3)
1.5						B (4.2) / C (3.3)	
2.2		A (4.6)	A (4.3)	A (5.9) / B (3.5)	A (5.2) / B (3.0)	B (2.5) / C (2.2)	
3.3			A (3.4) / B (3.0)	B (2.7) / C (3.7)	B (3.0) / C (2.0)	B (2.5, 3.5) / C (1.7)	D (1.7)
4.7		A (2.9) / B (2.7)	A (2.9) / B (2.1)	A (5.0) / B (2.9, 1.9) / C (1.7)	A (5.0) / B (2.8) / C (1.6)	B (3.1) / C (1.3) / D (1.0)	C (1.5) / D (0.
6.8		A (2.6)	A (2.6, 2.0) / B (1.8) / C (1.7)		B (2.4) / C (1.4)	C (1.8) / D (0.9)	D (0.9)
10	A (3.4, 2.7)	A (3.4, 2.0) / B (1.8) / C (1.8, 1.7)	B (2.0) / C (1.4, 0.8)	C (1.1)	C (1.1) / D (0.9)	C (1.6) / D (0.25, 0.3, 0.7)	D (0.8) / E (0.3
15 B (1.8) A (2.9, 2.0) / B (2.0, 1.8, 1.5) / C (1.8, 1.4)		B (2.0) / C (1.0)	B (2.0) / C (1.0) / D (0.9)	B (1.4, 2.0) / C (1.2) / D (0.7)	D (0.7)		
22	B (2.0, 1.5)	B (1.5) / C (1.5, 1.1)	B (1.9) / C (0.8, 1.0) / D (0.8)	C (1.0) / D (0.7)	D (0.6)	D (0.3, 0.6) / E (0.5)	
33	B (1.9, 1.7)	B (1.9, 1.4) / D (0.8)	C (0.9, 0.6) / D (0.6)	D (0.6)	D (0.5)		
47	B (1.8) / C (0.8)	B (1.8) / C (0.8, 0.5) / D (0.6)	C (0.8, 0.6) / D (0.6)	D (0.7) / E (0.6)	E (0.6)		
68	B (1.8)	C (1.0, 0.8) / D (1.0, 0.6, 0.4)	D (0.6)	E (0.6)			
100	E (0.3)	C (0.9, 0.5) / D (0.6)	D (0.6) / E (0.6, 0.15)				
150		D (0.6)					
220		E (0.5)					

Note

ESR limits in Ω are shown in parenthesis

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Marking

Capacitor marking includes an anode (+) polarity band, capacitance in microfarads and the voltage rating. "A" case capacitors use a letter code for the voltage and EIA capacitance code.

The Vishay identification marking is included if space permits. Vishay marking ("circled 2") may show additives in the form of short lines, depicting actual manufacturing facility. For A case capacitors discontinuation in polarity bar maybe used as actual manufacturing facility designation. Capacitors rated at 6.3 V are marked 6 V.

A manufacturing date code is marked on all capacitors. for details see FAQ: <u>www.vishay.com/doc?40110</u>.

Call the factory for further explanation.

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CAPACITANCE (μF)	CASE CODE	PART NUMBER	MAX. DCL AT +25 °C (μΑ)	MAX. DF AT +25 °C (%)	MAX. ESR AT +25 °C 100 kHz (Ω)	MAX. RIPPLE 100 kHz I _{RMS} (A)
		6.3 V _{DC} AT +85 °C; 4 V _{DC} A	T +125 °C; 3.15 V	_{DC} AT +150 °C		
10	А	TH3A106(1)6R3(3)3400	0.6	6	3.40	0.15
10	А	TH3A106(1)6R3(3)2700	0.6	6	2.70	0.17
15	В	TH3B156(1)6R3(2)1800	0.9	6	1.80	0.22
22	В	TH3B226(1)6R3(2)2000	1.3	6	2.00	0.21
22	В	TH3B226(1)6R3(2)1500	1.3	6	1.50	0.24
33	В	TH3B336(1)6R3(2)1900	2.0	6	1.90	0.21
33	В	TH3B336(1)6R3(2)1700	2.0	6	1.70	0.22
47	В	TH3B476(1)6R3(2)1800	2.8	8	1.80	0.22
47	С	TH3C476(1)6R3(3)0800	2.8	6	0.80	0.37
68	В	TH3B686(1)6R3(2)1800	4.1	6	1.80	0.22
100	E	TH3E107(1)6R3(4)0300	6.0	6	0.30	0.74
		10 V _{DC} AT +85 °C; 7 V _{DC}	AT +125 °C; 5 V _{DC}	AT +150 °C		
2.2	А	TH3A225(1)010(3)4600	0.5	6	4.60	0.13
4.7	А	TH3A475(1)010(3)2900	0.5	6	2.90	0.16
4.7	В	TH3B475(1)010(2)2700	0.5	6	2.70	0.18
6.8	А	TH3A685(1)010(3)2600	6.8	6	2.60	0.17
10	А	TH3A106(1)010(3)3400	1.0	6	3.40	0.15
10	А	TH3A106(1)010(3)2000	1.0	6	2.00	0.19
10	В	TH3B106(1)010(2)1800	1.0	6	1.80	0.22
10	С	TH3C106(1)010(3)1800	1.0	6	1.80	0.25
10	С	TH3C106(1)010(3)1700	1.0	6	1.70	0.25
15	А	TH3A156(1)010(3)2900	1.0	6	2.90	0.16
15	А	TH3A156(1)010(3)2000	1.0	6	2.00	0.19
15	В	TH3B156(1)010(2)2000	1.0	6	2.00	0.21
15	В	TH3B156(1)010(2)1800	1.0	6	1.80	0.22
15	В	TH3B156(1)010(2)1500	1.0	6	1.50	0.24
15	С	TH3C156(1)010(3)1800	1.0	6	1.80	0.25
15	С	TH3C156(1)010(3)1400	1.0	6	1.40	0.28

Note

Part number definitions:

(1) Capacitance tolerance: K, M

(2) Termination and packaging: C, D, E, F

(3) Termination and packaging: A, B, C, D, E, F

(4) Termination and packaging: A, B, C, D, E, F, V, U, T, W

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CAPACITANCE (μF)	CASE CODE	PART NUMBER	MAX. DCL AT +25 °C (μΑ)	MAX. DF AT +25 °C (%)	MAX. ESR AT +25 °C 100 kHz (Ω)	MAX. RIPPLI 100 kHz I _{RMS} (A)
		10 V _{DC} AT +85 °C; 7 V _{DC}	AT +125 °C: 5 Vpc	AT +150 °C	(/	(* 4
22	В	TH3B226(1)010(2)1500	2.2	6	1.50	0.24
22	C	TH3C226(1)010(2)1500	2.2	6	1.50	0.27
22	C	TH3C226(1)010(3)1100	2.2	6	1.10	0.32
33	В	TH3B336(1)010(2)1900	3.3	6	1.90	0.32
33	B	., .,	3.3	6	1.40	0.21
33	D	TH3B336(1)010(2)1400	3.3	6	0.80	0.23
		TH3D336(1)010(4)0800				
47	В	TH3B476(1)010(2)1800	4.7	6	1.80	0.22
47	С	TH3C476(1)010(3)0800	4.7	6	0.80	0.37
47	С	TH3C476(1)010(3)0500	4.7	6	0.50	0.47
47	D	TH3D476(1)010(4)0600	4.7	6	0.60	0.50
68	С	TH3C686(1)010(3)1000	6.8	8	1.00	0.33
68	С	TH3C686(1)010(3)0800	6.8	8	0.80	0.37
68	D	TH3D686(1)010(4)1000	6.8	6	1.00	0.39
68	D	TH3D686(1)010(4)0600	6.8	6	0.60	0.50
68	D	TH3D686(1)010(4)0400	6.8	6	0.40	0.61
100	С	TH3C107(1)010(3)0900	10.0	6	0.90	0.35
100	С	TH3C107(1)010(3)0500	10.0	6	0.50	0.47
100	D	TH3D107(1)010(4)0600	10.0	8	0.60	0.50
150	D	TH3D157(1)010(4)0600	15.0	8	0.60	0.50
220	E	TH3E227(1)010(4)0500	22.0	8	0.50	0.61
220	-	16 V _{DC} AT +85 °C; 10 V _{DC}		-	0.00	0.01
1.0	A	TH3A105(1)016(3)6500	0.5	4	6.50	0.11
2.2	A	TH3A225(1)016(3)4300	0.5	6	4.30	0.13
3.3	A	TH3A335(1)016(3)3400	0.5	6	3.40	0.15
3.3	В	TH3B335(1)016(2)3000	0.5	6	3.00	0.17
4.7	A	TH3A475(1)016(3)2900	0.8	6	2.90	0.16
4.7	В	TH3B475(1)016(2)2100	0.8	6	2.10	0.2
6.8	A	TH3A685(1)016(3)2600	1.1	6	2.60	0.17
6.8	A	TH3A685(1)016(3)2000	1.1	6	2.00	0.19
6.8	В	TH3B685(1)016(2)1800	1.1	6	1.80	0.22
6.8	С	TH3C685(1)016(3)1700	1.1	6	1.70	0.25
10	В	TH3B106(1)016(2)2000	1.6	6	2.00	0.21
10	С	TH3C106(1)016(3)1400	1.6	6	1.40	0.28
10	C	TH3C106(1)016(3)0800	1.6	6	0.80	0.37
15	В	TH3B156(1)016(2)2000	2.4	6	2.00	0.21
15	C	TH3C156(1)016(3)1000	2.4	6	1.00	0.33
22	В	TH3B226(1)016(2)1900	3.5	6	1.90	0.21
22	C	TH3C226(1)016(3)1000	3.5	6	1.00	0.33
22	c		3.5	4.5	0.80	0.33
		TH3C226(1)016(3)0800				
22	D	TH3D226(1)016(4)0800	3.5	6	0.80	0.43
33	С	TH3C336(1)016(3)0900	5.3	6	0.90	0.35
33	С	TH3C336(1)016(3)0600	5.3	6	0.60	0.43
33	D	TH3D336(1)016(4)0600	5.3	6	0.60	0.50
47	С	TH3C476(1)016(3)0800	7.5	6	0.80	0.37
47	С	TH3C476(1)016(3)0600	7.5	6	0.60	0.43
47	D	TH3D476(1)016(4)0600	7.5	6	0.60	0.43
68	D	TH3D686(1)016(4)0600	10.9	6	0.60	0.50
100	D	TH3D107(1)016(4)0600	16.0	8	0.60	0.50
100	E	TH3E107(1)016(4)0600	16.0	8	0.60	0.56
100	E	TH3E107(1)016(4)0150	16.0	8	0.15	1.11

Note

Part number definitions: .

(1) Capacitance tolerance: K, M(2) Termination and packaging: C, D, E, F

(3) Termination and packaging: A, B, C, D, E, F
(4) Termination and packaging: A, B, C, D, E, F, V, U, T, W

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STANDARD	RATINGS					
CAPACITANCE (µF)	CASE CODE	PART NUMBER	MAX. DCL AT +25 °C (μΑ)	MAX. DF AT +25 °C (%)	MAX. ESR AT +25 °C 100 kHz (Ω)	MAX. RIPPLE 100 kHz I _{RMS} (A)
		20 V _{DC} AT +85 °C; 13 V _{DC}	AT +125 °C; 10 V	oc AT +150 °C		
1.0	А	TH3A105(1)020(3)5900	0.5	4	5.90	0.11
2.2	А	TH3A225(1)020(3)5900	0.5	6	5.90	0.11
2.2	В	TH3B225(1)020(2)3500	0.5	6	3.50	0.16
3.3	В	TH3B335(1)020(2)2700	0.7	6	2.70	0.18
3.3	С	TH3C335(1)020(3)2700	0.7	6	2.70	0.20
4.7	А	TH3A475(1)020(3)5000	0.9	6	5.00	0.12
4.7	В	TH3B475(1)020(2)1900	0.9	6	2.90	0.17
4.7	В	TH3B475(1)020(2)2900	0.9	6	1.90	0.21
4.7	С	TH3C475(1)020(3)1700	0.9	6	1.70	0.25
10	С	TH3C106(1)020(3)1100	2.0	6	1.10	0.32
15	В	TH3B156(1)020(2)2000	3.0	6	2.00	0.21
15	C	TH3C156(1)020(3)1000	3.0	6	1.00	0.33
15	D	TH3D156(1)020(4)0900	3.0	6	0.90	0.41
22	C	TH3C226(1)020(3)1000	4.4	6	1.00	0.33
22	D	TH3D226(1)020(4)0700	4.4	6	0.70	0.46
33	D	TH3D336(1)020(4)0600	6.6	6	0.60	0.5
47	D	TH3D476(1)020(4)0700	9.4	6	0.70	0.46
47	E	TH3E476(1)020(4)0600	9.4	8	0.60	0.56
68	E	TH3E686(1)020(4)0600	13.6	8	0.60	0.56
	E	25 V _{DC} AT +85 °C; 17 V _{DC} A			0.00	0.00
0.47	А	TH3A474(1)025(3)14R0	0.5	4	14.00	0.073
1.0	A	TH3A105(1)025(3)5200	0.5	4	5.20	0.12
1.0	A	TH3A105(1)025(3)3000	0.5	4	3.00	0.16
1.0	В	TH3B105(1)025(2)5000	0.5	4	5.00	0.13
2.2	A	TH3A225(1)025(3)5200	0.6	6	5.20	0.12
2.2	В	TH3B225(1)025(2)3000	0.6	6	3.00	0.17
3.3	В	TH3B335(1)025(2)3000	0.8	6	3.00	0.17
3.3	C	TH3C335(1)025(3)2000	0.8	6	2.00	0.23
4.7	A	TH3A475(1)025(3)5000	1.2	6	5.00	0.12
4.7	В	TH3B475(1)025(2)2800	1.2	6	2.80	0.12
4.7	C	TH3C475(1)025(3)1600	1.2	6	1.60	0.26
6.8	В	TH3B685(1)025(2)2400	1.7	6	2.40	0.20
6.8	С	TH3C685(1)025(3)1400	1.7	6	1.40	0.28
10	C	., .,	2.5	6	1.40	0.28
10	D	TH3C106(1)025(3)1100	2.5 2.5		0.90	
10	B	TH3D106(1)025(4)0900 TH3B156(1)025(2)2000	2.5 3.8	6 6	0.90 2.00	0.41 0.21
	B					
15 15		TH3B156(1)025(2)1400 TH3C156(1)025(3)1200	3.8	6	1.40	0.25
	С	., .,	3.8	6	1.20	0.30
15	D	TH3D156(1)025(4)0700	3.8	6	0.70	0.46
22	D	TH3D226(1)025(4)0600	5.5	6	0.60	0.50
33	D	TH3D336(1)025(4)0500	8.3	6	0.50	0.55
47	E	TH3E476(1)025(4)0600	11.8	6	0.60	0.56

Note •

Part number definitions:

(1) Capacitance tolerance: K, M

(1) Suparticle tolerance. N, M
(2) Termination and packaging: C, D, E, F
(3) Termination and packaging: A, B, C, D, E, F
(4) Termination and packaging: A, B, C, D, E, F, V, U, T, W

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STANDARD	RATINGS					
CAPACITANCE (µF)	CASE CODE	PART NUMBER	MAX. DCL AT +25 °C (μΑ)	MAX. DF AT +25 °C (%)	MAX. ESR AT +25 °C 100 kHz (Ω)	MAX. RIPPLE 100 kHz I _{RMS} (A)
		35 V _{DC} AT +85 °C; 23 V _{DC} A	AT +125 °C; 17.5 V	_{DC} AT +150 °C		
0.33	А	TH3A334(1)035(3)11R0	0.5	4	11.00	0.08
1.0	А	TH3A105(1)035(3)6600	0.5	4	6.60	0.11
1.0	В	TH3B105(1)035(2)4400	0.5	4	4.40	0.14
1.5	В	TH3B155(1)035(2)4200	0.5	6	4.20	0.14
1.5	С	TH3C155(1)035(3)3300	0.5	6	3.30	0.18
2.2	В	TH3B225(1)035(2)2500	0.8	6	2.50	0.18
2.2	С	TH3C225(1)035(3)2200	0.8	6	2.20	0.22
3.3	В	TH3B335(1)035(2)3500	1.2	6	3.50	0.16
3.3	В	TH3B335(1)035(2)2500	1.2	6	2.50	0.18
3.3	С	TH3C335(1)035(3)1700	1.2	6	1.70	0.25
4.7	В	TH3B475(1)035(2)3100	1.7	6	3.10	0.17
4.7	С	TH3C475(1)035(3)1300	1.6	6	1.30	0.29
4.7	D	TH3D475(1)035(4)1000	1.6	6	1.00	0.39
6.8	С	TH3C685(1)035(3)1800	2.4	6	1.80	0.25
6.8	D	TH3D685(1)035(4)0900	2.4	6	0.90	0.41
10	С	TH3C106(1)035(3)1600	3.5	6	1.60	0.26
10	D	TH3D106(1)035(4)0700	3.5	6	0.70	0.46
10	D	TH3D106(1)035(4)0300	3.5	6	0.30	0.71
10	D	TH3D106(1)035(4)0250	3.5	6	0.25	0.77
15	D	TH3D156(1)035(4)0700	5.3	6	0.70	0.46
22	D	TH3D226(1)035(4)0600	7.7	6	0.60	0.50
22	D	TH3D226(1)035(4)0300	7.7	6	0.30	0.71
22	E	TH3E226(1)035(4)0500	7.7	6	0.50	0.61
		50 V _{DC} AT +85 °C; 33 V _{DC}	AT +125 °C; 25 V _D	_{oc} AT +150 °C		
1.0	С	TH3C105(1)050(3)3300	0.5	4	3.30	0.18
3.3	D	TH3D335(1)050(4)1700	1.7	6	1.70	0.30
4.7	С	TH3C475(1)050(3)1500	2.4	6	1.50	0.27
4.7	D	TH3D475(1)050(4)0900	2.4	6	0.90	0.41
6.8	D	TH3D685(1)050(4)0900	3.4	6	0.90	0.41
10	D	TH3D106(1)050(4)0800	5.0	6	0.80	0.43
10	E	TH3E106(1)050(4)0500	5.0	6	0.50	0.61

Note

•

Part number definitions:

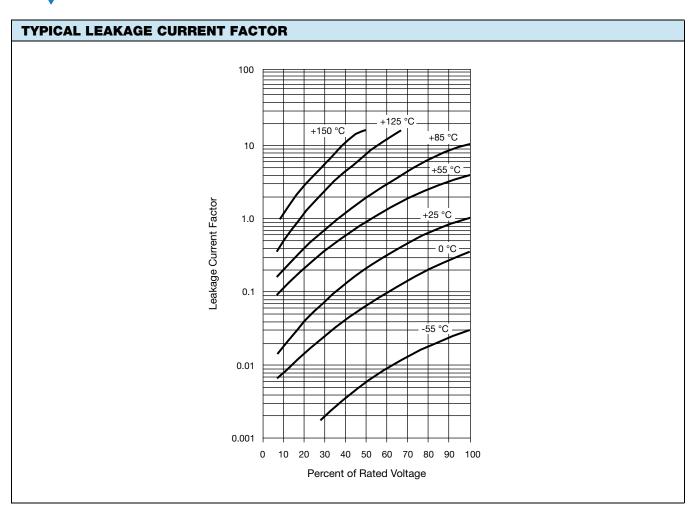
(1) Capacitance tolerance: K, M

(2) Termination and packaging: C, D, E, F
(3) Termination and packaging: A, B, C, D, E, F
(4) Termination and packaging: A, B, C, D, E, F, V, U, T, W



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ТН3



Note

- At +25 °C, the leakage current shall not exceed the value listed in the Standard Ratings table. •
 - At +85 °C, the leakage current shall not exceed 10 times the value listed in the Standard Ratings table.

At +125 °C, the leakage current shall not exceed 12 times the value listed in the Standard Ratings table.

At +150 °C, the leakage current shall not exceed 15 times the value listed in the Standard Ratings table

POWER DISSIPATION	
CASE CODE	MAXIMUM PERMISSIBLE POWER DISSIPATION AT +25 $^\circ$ C (W) IN FREE AIR
A	0.075
В	0.085
С	0.110
D	0.150
E	0.165

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Е

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	STANDARD PACKAGING QUAN	тіту				
		UNITS PER REEL				
	CASE CODE	7" REEL	13" REEL			
	A	2000	9000			
	В	2000	8000			
	С	500	3000			
	D	500	2500			

PRODUCT INFORMATION	
Guide for Molded Tantalum Capacitors	
Pad Dimensions	www.vishay.com/doc?40074
Package Dimensions	
Moisture Sensitivity	www.vishay.com/doc?40135
SELECTOR GUIDES	
Solid Tantalum Selector Guide	www.vishay.com/doc?49053
Solid Tantalum Chip Capacitors	www.vishay.com/doc?40091
FAQ	
Frequently Asked Questions	www.vishay.com/doc?40110

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Guide for Molded Tantalum Capacitors

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum / tantalum oxide / manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve"metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance / volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance / volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS					
DIELECTRIC	e DIELECTRIC CONSTANT				
Air or vacuum	1.0				
Paper	2.0 to 6.0				
Plastic	2.1 to 6.0				
Mineral oil	2.2 to 2.3				
Silicone oil	2.7 to 2.8				
Quartz	3.8 to 4.4				
Glass	4.8 to 8.0				
Porcelain	5.1 to 5.9				
Mica	5.4 to 8.7				
Aluminum oxide	8.4				
Tantalum pentoxide	26				
Ceramic	12 to 400K				

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{eA}{t}$$

where

C = capacitance

e = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.



SOLID ELECTROLYTE TANTALUM CAPACITORS

Solid electrolyte capacitors contain manganese dioxide, which is formed on the tantalum pentoxide dielectric layer by impregnating the pellet with a solution of manganous nitrate. The pellet is then heated in an oven, and the manganous nitrate is converted to manganese dioxide.

The pellet is next coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the pellet and the Leadframe.

Molded Chip tantalum capacitor encases the element in plastic resins, such as epoxy materials. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for consumer and commercial electronics with the added feature of low cost

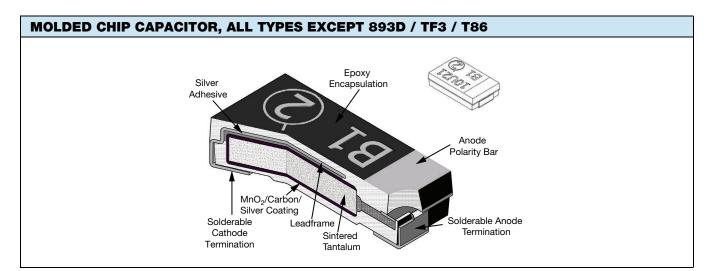
Surface mount designs of "Solid Tantalum" capacitors use lead frames or lead frameless designs as shown in the accompanying drawings.

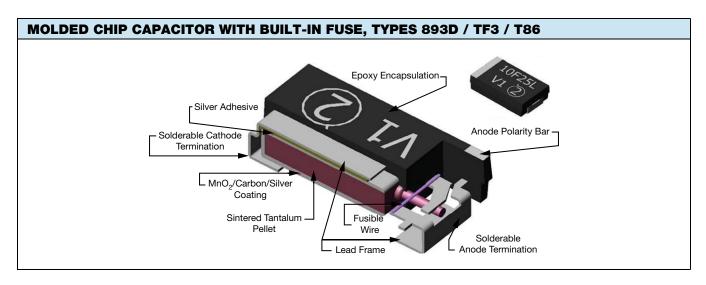
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TANTALUM CAPACITORS FOR ALL DESIGN CONSIDERATIONS

Solid electrolyte designs are the least expensive for a given rating and are used in many applications where their very small size for a given unit of capacitance is of importance. They will typically withstand up to about 10 % of the rated DC working voltage in a reverse direction. Also important are their good low temperature performance characteristics and freedom from corrosive electrolytes.

Vishay Sprague patented the original solid electrolyte capacitors and was the first to market them in 1956. Vishay Sprague has the broadest line of tantalum capacitors and has continued its position of leadership in this field. Data sheets covering the various types and styles of Vishay Sprague capacitors for consumer and entertainment electronics, industry, and military applications are available where detailed performance characteristics must be specified.





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2 For technical questions, contact: <u>tantalum@vishay.com</u> Document Number: 40074

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COMMERCIAL PRODUCTS

SOLID TANTALUM CAPACITORS - MOLDED CASE								
SERIES	293D	793DX-CTC3- CTC4	593D	TR3	TP3	TL3		
PRODUCT IMAGE		In the tree trees		Line Line		47875 80-2		
TYPE		Surface mo	ount TANTAMOUNT	™, molded case	-			
FEATURES	Standard industrial grade	CECC approved	Low ESR	Low ESR	High performance, automotive grade	Very low DCL		
TEMPERATURE RANGE			-55 °(C to +125 °C				
CAPACITANCE RANGE	0.1 μF to 1000 μF	0.1 μF to 100 μF	1 µF to 470 µF	0.47 μF to 1000 μF	0.1 μF to 470 μF	0.1 μF to 470 μF		
VOLTAGE RANGE	4 V to 75 V	4 V to 50 V	4 V to 50 V	4 V to 75 V	4 V to 50 V	4 V to 50 V		
CAPACITANCE TOLERANCE		± 10 %, ± 20 %						
LEAKAGE CURRENT		0.01 CV or 0.5 μA, whichever is greater						
DISSIPATION FACTOR	4 % to 30 %	4 % to 6 %	4 % to 15 %	4 % to 30 %	4 % to 15 %	4 % to 15 %		
CASE CODES	A, B, C, D, E, V	A, B, C, D	A, B, C, D, E	A, B, C, D, E, V, W	A, B, C, D, E	A, B, C, D, E		
TERMINATION		10	00 % matte tin sta	andard, tin / lead availa	ole			

SOLID TANTAL	ALUM CAPACITORS - MOLDED CASE					
SERIES	TH3	TH4	TH5	893D	TF3	
PRODUCT IMAGE		22816	1902 4:3054	THE SUL	177 50 177 50 177 50 177 50	
ТҮРЕ		Surface	mount Tantamount™, m	olded case		
FEATURES	High temperature +150 °C, automotive grade	High temperature +175 °C, automotive grade	Very high temperature +200 °C	Built-in fuse	Built-in fuse, low ESR	
TEMPERATURE RANGE	-55 °C to +150 °C -55 °C to +175 °C -55 °C to +200 °C -55 °C to +125 °C					
CAPACITANCE RANGE	0.33 µF to 220 µF	10 µF to 100 µF	4.7 μF to 100 μF	0.47 μF to 680 μF	0.47 μF to 470 μF	
VOLTAGE RANGE	6.3 V to 50 V	6.3 V to 35 V	5 V to 24 V	4 V to 50 V	4 V to 50 V	
CAPACITANCE TOLERANCE			± 10 %, ± 20 %			
LEAKAGE CURRENT	0.01 CV or 0.5 μA, whichever is greater					
DISSIPATION FACTOR	4 % to 8 %	4.5 % to 8 %	6 % to 10 %	6 % to 15 %	6 % to 15 %	
CASE CODES	A, B, C, D, E	B, C, D, E	D, E	C, D, E	C, D, E	
TERMINATION	100 % matte tin standard, tin / lead and gold plated available	100 % matte tin	Gold plated	100 % matte	tin standard	

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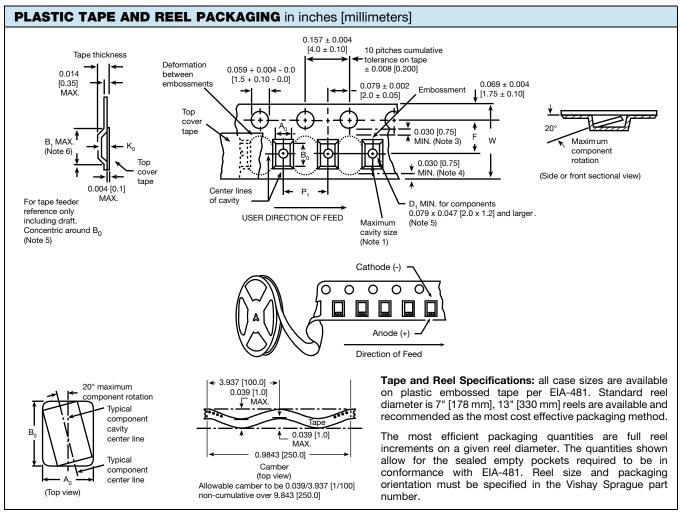
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HIGH RELIABILITY PRODUCTS

SOLID TANTA	SOLID TANTALUM CAPACITORS - MOLDED CASE					
SERIES	ТМЗ	Т83	T86	CWR11	95158	
PRODUCT IMAGE	1945 D5 Unrel D6 D6 D6 D6 D6 D6 D6 D6 D6 D6 D6 D6 D6	47715 ro 3				
ТҮРЕ	Tantamount™, molded case, Hi-Rel.		TANTAMOUNT™, molded case, Hi-Rel. COTS TANTAMOUNT™, molded case, DLA approved			
FEATURES	High reliability, for Medical Instruments	High reliability, standard and low ESR	High reliability, built-in fuse, standard and low ESR	MIL-PRF-55365/8 qualified	Low ESR	
TEMPERATURE RANGE			-55 °C to +	125 °C		
CAPACITANCE RANGE	1 μF to 220 μF	0.1 μF to 470 μF	0.47 μF to 330 μF	0.1 μF to 100 μF	4.7 μF to 220 μF	
VOLTAGE RANGE	4 V to 20 V	4 V to 63 V		4 V to 50 V		
CAPACITANCE TOLERANCE	E	± 10 %, ± 20 % ± 5 %, ± 10 %, ± 20 % ± 10 %, ± 20 %				
LEAKAGE CURRENT	0.005 CV or 0.25 μA, whichever is greater	0.01 CV or 0.5 μA, whichever is greater				
DISSIPATION FACTOR	4 % to 8 %	4 % to 15 %	6 % to 16 %	4 % to 6 %	4 % to 12 %	
CASE CODES	A, B, C, D, E	A, B, C, D, E	C, D, E	A, B, C, D	C, D, E	
TERMINATION	100 % matte tin; tin / lead	100 % matte tin; tin / lead; tin / lead solder fused	100 % matte tin	Tin / lead; tin / lead solder fused	Tin / lead solder plated; gold plated	

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Notes

- · Metric dimensions will govern. Dimensions in inches are rounded and for reference only.
- (1) A₀, B₀, K₀, are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A₀, B₀, K₀) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°.
- (2) Tape with components shall pass around radius "R" without damage. The minimum trailer length may require additional length to provide "R" minimum for 12 mm embossed tape for reels with hub diameters approaching N minimum.
- (3) This dimension is the flat area from the edge of the sprocket hole to either outward deformation of the carrier tape between the embossed cavities or to the edge of the cavity whichever is less.
- (4) This dimension is the flat area from the edge of the carrier tape opposite the sprocket holes to either the outward deformation of the carrier tape between the embossed cavity or to the edge of the cavity whichever is less.
- ⁽⁵⁾ The embossed hole location shall be measured from the sprocket hole controlling the location of the embossement. Dimensions of embossement location shall be applied independent of each other.
- $^{(6)}$ B₁ dimension is a reference dimension tape feeder clearance only.

CASE CODE	TAPE SIZE	В ₁ (МАХ.)	D ₁ (MIN.)	F	К ₀ (МАХ.)	P ₁	w
MOLDED		CITORS; ALL TY	'PES				
A	8 mm	0.165	0.039	0.138 ± 0.002	0.094	0.157 ± 0.004	0.315 ± 0.012
В	0 11111	[4.2]	[1.0]	[3.5 ± 0.05]	[2.4]	$[4.0 \pm 1.0]$	$[8.0 \pm 0.30]$
С							
D		0.00	0.050	0.017 . 0.00	0 177	0.015 . 0.004	0.470 . 0.010
E	12 mm	0.32 [8.2]	0.059 [1.5]	0.217 ± 0.00 [5.5 ± 0.05]	0.177 [4.5]	0.315 ± 0.004 [8.0 ± 1.0]	0.472 ± 0.012 [12.0 ± 0.30]
V		[0.2]	[1.0]	[0.0 ± 0.00]	[5]	[0.0 ± 1.0]	[12.0 ± 0.00]
W							

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RECOMMENDED REFLOW PRO	FILES	
Capacitors should withstand reflow profile as	per J-STD-020 standard, three cycles.	
	Max. ramp-up rate = 3 °C/s Max. ramp-down rate = 6 °C/s t_p max. Preheat area t_s Time 25 °C to peak TIME (s)	← T _c -5°C
PROFILE FEATURE	SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY
Preheat / soak		
Temperature min. (T _{s min.})	100 °C	150 °C
Temperature max. (T _{s max.})	150 °C	200 °C
Time (t_s) from ($T_s _{min.}$ to $T_s _{max.}$)	60 s to 120 s	60 s to 120 s
Ramp-up		
Ramp-up rate (T _L to T _p)	3 °C/s max.	3 °C/s max.
	3 ℃/s max. 183 ℃	3 °C/s max. 217 °C
Ramp-up rate (T _L to T _p)		
Ramp-up rate (T_L to T_p) Liquidus temperature (T_L) Time (t_L) maintained above T_L Peak package body temperature (T_p)	183 °C 60 s to 150 s	217 °C
Ramp-up rate (T_L to T_p) Liquidus temperature (T_L) Time (t_L) maintained above T_L	183 °C 60 s to 150 s	217 °C 60 s to 150 s
Ramp-up rate (T_L to T_p) Liquidus temperature (T_L) Time (t_L) maintained above T_L Peak package body temperature (T_p) Time (t_p) within 5 °C of the specified	183 °C 60 s to 150 s Depends on case si	217 °C 60 s to 150 s ze - see table below
Ramp-up rate (T_L to T_p) Liquidus temperature (T_L) Time (t_L) maintained above T_L Peak package body temperature (T_p) Time (t_p) within 5 °C of the specified classification temperature (T_C)	183 °C 60 s to 150 s Depends on case si 20 s	217 °C 60 s to 150 s ze - see table below 30 s

PEAK PACKAGE BODY TEMPERATURE (Tp)			
CASE CODE	PEAK PACKAGE BODY TEMPERATURE (Tp)		
CASE CODE	SnPb EUTECTIC PROCESS	LEAD (Pb)-FREE PROCESS	
A, B, C, V	235 °C	260 °C	
D, E, W	220 °C	250 °C	

PAD DIMENSIONS	PAD DIMENSIONS in inches [millimeters]					
		D → C → , +				
CASE CODE	A (MIN.)	В (NOM.)	С (NOM.)	D (NOM.)		
MOLDED CHIP CAPACI	TORS, ALL TYPES			·		
А	0.071 [1.80]	0.067 [1.70]	0.053 [1.35]	0.187 [4.75]		
В	0.118 [3.00]	0.071 [1.80]	0.065 [1.65]	0.207 [5.25]		
С	0.118 [3.00]	0.094 [2.40]	0.118 [3.00]	0.307 [7.80]		
D	0.157 [4.00]	0.098 [2.50]	0.150 [3.80]	0.346 [8.80]		
E	0.157 [4.00]	0.098 [2.50]	0.150 [3.80]	0.346 [8.80]		
V	0.157 [4.00]	0.098 [2.50]	0.150 [3.80]	0.346 [8.80]		
W	0.185 [4.70]	0.098 [2.50]	0.150 [3.80]	0.346 [8.80]		

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GUIDE TO APPLICATION

1 AC Ripple Current: the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

- P = power dissipation in W at +25 °C as given in the tables in the product datasheets (Power Dissipation).
- R_{ESR} = the capacitor equivalent series resistance at the specified frequency
- 2. AC Ripple Voltage: the maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

or, from the formula:

$$V_{\rm RMS} = Z_{\rm V} \frac{P}{R_{\rm ESR}}$$

where.

- power dissipation in W at +25 °C as given in P = the tables in the product datasheets (Power Dissipation).
- R_{ESR} = the capacitor equivalent series resistance at the specified frequency
- Z = the capacitor impedance at the specified frequency
- 2.1 The sum of the peak AC voltage plus the applied DC voltage shall not exceed the DC voltage rating of the capacitor.
- 2.2 The sum of the negative peak AC voltage plus the applied DC voltage shall not allow a voltage reversal exceeding 10 % of the DC working voltage at +25 °C.
- З. Reverse Voltage: solid tantalum capacitors are not intended for use with reverse voltage applied. However, they have been shown to be capable of withstanding momentary reverse voltage peaks of up to 10 % of the DC rating at 25 °C and 5 % of the DC rating at +85 °C.
- 4. Temperature Derating: if these capacitors are to be operated at temperatures above +25 °C, the permissible RMS ripple current shall be calculated using the derating factors as shown:

TEMPERATURE (°C)	DERATING FACTOR
+25	1.0
+85	0.9
+125	0.4
+150 (1)	0.3
+175 (1)	0.2
+200 (1)	0.1

Note

⁽¹⁾Applicable for dedicated high temperature product series

5. Power Dissipation: power dissipation will be affected by the heat sinking capability of the mounting surface. Non-sinusoidal ripple current may produce heating effects which differ from those shown. It is important that the equivalent I_{BMS} value Vishay Sprague

be established when calculating permissible operating levels. (Power dissipation calculated using +25 °C temperature rise).

6. Printed Circuit Board Materials: molded capacitors are compatible with commonly used printed circuit board materials (alumina substrates, FR4, FR5, G10, PTFE-fluorocarbon and porcelanized steel).

7. Attachment:

- Solder Paste: the recommended thickness of the 7.1 solder paste after application is 0.007" ± 0.001" [0.178 mm ± 0.025 mm]. Care should be exercised in selecting the solder paste. The metal purity should be as high as practical. The flux (in the paste) must be active enough to remove the oxides formed on the metallization prior to the exposure to soldering heat. In practice this can be aided by extending the solder preheat time at temperatures below the liquidous state of the solder.
- Soldering: capacitors can be attached by conventional soldering techniques; vapor phase, 7.2 convection reflow, infrared reflow, wave soldering, and hot plate methods. The soldering profile charts show recommended time / temperature conditions for soldering. Preheating is recommended. The recommended maximum ramp rate is 2 °C per s. Attachment with a soldering iron is not recommended due to the difficulty of controlling temperature and time at temperature. The soldering iron must never come in contact with the capacitor.
- Backward and Forward Compatibility: capacitors 7.2.1 with SnPb or 100 % tin termination finishes can be soldered using SnPb or lead (Pb)-free soldering processes.
- 8. Cleaning (Flux Removal) After Soldering: molded capacitors are compatible with all commonly used solvents such as TES, TMS, Prelete, Chlorethane, Terpene and aqueous cleaning media. However, CFC / ODS products are not used in the production of these devices and are not recommended. Solvents containing methylene chloride or other epoxy solvents should be avoided since these will attack the epoxy encapsulation material.
- 8.1 When using ultrasonic cleaning, the board may resonate if the output power is too high. This vibration can cause cracking or a decrease in the adherence of the termination. DO NOT EXCEED 9W/I at 40 kHz for 2 min.
- Recommended Mounting Pad Geometries: proper 9 mounting pad geometries are essential for successful solder connections. These dimensions are highly process sensitive and should be designed to minimize component rework due to unacceptable solder joints. The dimensional configurations shown are the recommended pad geometries for both wave and reflow soldering techniques. These dimensions are intended to be a starting point for circuit board designers and may be fine tuned if necessary based upon the peculiarities of the soldering process and / or circuit board design.



Molded Chip Tantalum Capacitors, Automotive Grade

		ACTERISTICS				
ITEM		HARACTERISTICS				
Category temperature range				raph "Category Voltage	e vs. Temperature") ⁽¹⁾	
Capacitance tolerance		sted via bridge method				
Dissipation factor	Limits per Standard	Ratings table. Tested	via bridge method, a	t 25 °C, 120 Hz		
ESR	Limits per Standard	Ratings table. Tested	via bridge method, a	t 25 °C, 100 kHz		
Leakage current	resistor in series wit whichever is greater <i>"Typical Leakage Co</i>	h the capacitor under t r. Note that the leakage urrent Temperature Fac	est, leakage current a current varies with t	n using a steady source at 25 °C is not more tha emperature and applied ate adjustment factor.	n 0.01 CV or 0.5 µA,	
Capacitance change by temperature	+30 % max. (at +17 +20 % max. (at +12 +10 % max. (at +85 -10 % max. (at -55	5 °C and +150 °C) °C)				
Reverse voltage	10 % of the DC ration 5 % of the DC ration	Capacitors are capable of withstanding peak voltages in the reverse direction equal to: 10 % of the DC rating at +25 °C 5 % of the DC rating at +85 °C 1 % of the DC rating at +125 °C				
Ripple current	temperatures above derating factors: 1.0 at +25 °C 0.9 at +85 °C 0.4 at +125 °C 0.3 at +150 °C 0.2 at +175 °C	1.0 at +25 ℃ 0.9 at +85 ℃ 0.4 at +125 ℃ 0.3 at +150 ℃				
Maximum operating	+85 °C		+125 °C		+150 °C / +175 °C	
and surge voltages vs. temperature	RATED VOLTAGE (V)	SURGE VOLTAGE (V)	CATEGORY VOLTAGE (V)	SURGE VOLTAGE (V)	CATEGORY VOLTAGE (V)	
	4	5.2	2.7	3.4	n/a	
	6.3	8	4	5	3	
	10	13	7	8	5	
	16	20	10	12	8	
	20	26	13	16	10	
	25	32	17	20	12.5	
	35	46	23	28	17.5	
	50	65	33	40	25	
	50 ⁽²⁾	60	33	40	n/a	
	50 ⁽²⁾ 63 75 ⁽³⁾	60 75 75	33 42 50	40 50 50	n/a n/a	

Notes

All information presented in this document reflects typical performance characteristics

⁽¹⁾ Series TH3 - up to 150 °C; TH4 - up to 175 °C

⁽²⁾ Capacitance value 15 µF and higher

⁽³⁾ For 293D and TR3 only

RECOMMENDED VOLTAGE DERATING GUIDELINES (for temperature below +85 °C)					
VOLTAGE RAIL CAPACITOR VOLTAGE RATING					
≤ 3.3	6.3				
5	10				
10	20				
12	25				
15	35				
≥ 24	50 or series configuration				

Note

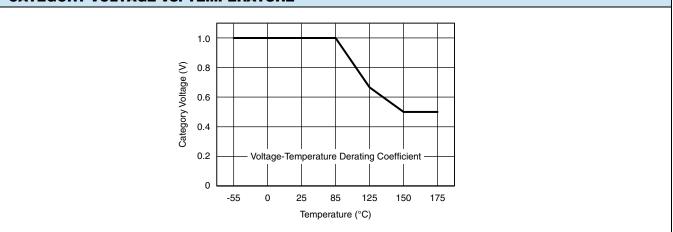
For temperatures above +85 °C the same voltage derating ratio is recommended, but with respect to category voltage.

Up to +85 °C: category voltage = rated voltage At +125 °C: category voltage = 2/3 of rated voltage

At 150 °C / 175 °C: category voltage = 1/2 of rated voltage

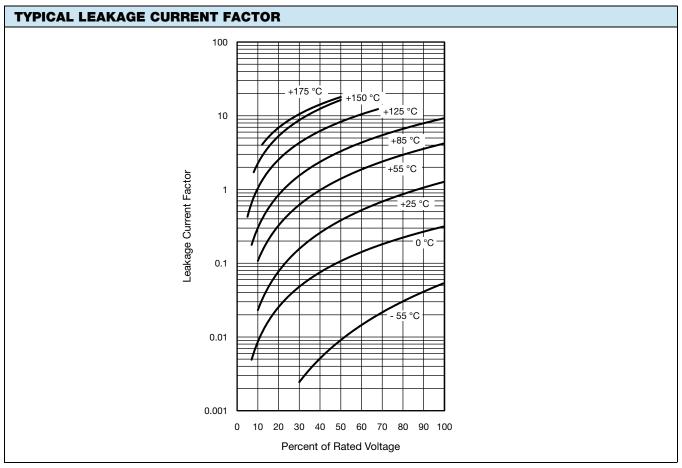


CATEGORY VOLTAGE VS. TEMPERATURE



Note

• Below 85 °C category voltage is equal to rated voltage



Note • At

At +25 °C, the leakage current shall not exceed the value listed in the Standard Ratings table.

At +85 °C, the leakage current shall not exceed 10 times the value listed in the Standard Ratings table.

At +125 °C, the leakage current shall not exceed 12 times the value listed in the Standard Ratings table.

At +150 °C, the leakage current shall not exceed 15 times the value listed in the Standard Ratings table.

At +175 °C, the leakage current shall not exceed 18 times the value listed in the Standard Ratings table

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ENVIRONMENTAL PERFORMANCE CHARACTERISTICS				
ITEM	CONDITION	POST TEST PERFOR	MANCE	
High temperature exposure (storage)	MIL-STD-202, method 108 1000 h, at maximum rated temperature, unpowered	Capacitance change Dissipation factor Leakage current ESR	Within ± 20 % of initial value Initial specified limit Initial specified limit Initial specified limit	
Operational life test at +125 °C	AEC-Q200 1000 h application 2/3 of rated voltage	Capacitance change Dissipation factor Leakage current ESR	Within ± 20 % of initial value Initial specified limit Shall not exceed 10 times the initial limit Initial specified limit	
Operational life test at +150 °C (for TH3) and at +175 °C (for TH4)	AEC-Q200 1000 h application 1/2 of rated voltage	Capacitance change Dissipation factor Leakage current ESR	Within \pm 20 % of initial value Shall not exceed 3 times the initial limit Shall not exceed 10 times the initial limit Shall not exceed 3 times the initial limit	
Surge voltage	MIL-PRF-55365: 1000 successive test cycles at 85 °C of surge voltage (as specified in the table above), in series with a 33 Ω resistor at the rate of 30 s ON, 30 s OFF	Capacitance change Dissipation factor Leakage current ESR	Within \pm 30 % of initial value Shall not exceed 1.5 times the initial limit Shall not exceed 2 times the initial limit Shall not exceed 1.5 times the initial limit	
Biased humidity test	AEC-Q200 At 85 °C / 85 % RH, 1000 h, with rated voltage applied	Capacitance change Dissipation factor Leakage current ESR	Within \pm 20 % of initial value Shall not exceed 3 times the initial limit Shall not exceed 10 times the initial limit Shall not exceed 3 times the initial limit	
Temperature cycling	AEC-Q200 / JESD22, method JA-104 -55 °C / +125 °C, for 1000 cycles	Capacitance change Dissipation factor Leakage current ESR	Within ± 20 % of initial value Initial specified limit Initial specified limit Initial specified limit	

MECHANICAL	PERFORMANCE CHARACTERISTICS	
ITEM	CONDITION	POST TEST PERFORMANCE
Vibration	MIL-STD-202, method 204: 10 Hz to 2000 Hz, 5 <i>g</i> peak for 20 min, 12 cycles each of 3 orientations (total 36 cycles), at rated voltage	Capacitance changeWithin ± 20 % of initial valueDissipation factorInitial specified limitLeakage currentInitial specified limit
		There shall be no mechanical or visual damage to capacitors post-conditioning.
Mechanical shock	MIL-STD-202, method 213, condition F, 1500 <i>g</i> peak, 0.5 ms, half-sine	Capacitance changeWithin ± 20 % of initial valueDissipation factorInitial specified limitLeakage currentInitial specified limit
		There shall be no mechanical or visual damage to capacitors post-conditioning.
Resistance to solder heat	MIL-STD-202, method 210, condition D Solder dip 260 °C \pm 5 °C, 10 s	Capacitance changeWithin ± 20 % of initial valueDissipation factorInitial specified limitLeakage currentInitial specified limit
Resistance to solvents	MIL-STD-202, method 215	Capacitance changeWithin ± 20 % of initial valueDissipation factorInitial specified limitLeakage currentInitial specified limit
		There shall be no mechanical or visual damage to capacitors post-conditioning. Body marking shall remain legible.
Solderability	AEC-Q200 / J-STD-002	Electrical test not required
Terminal strength / Shear force test	AEC-Q200-006 Apply a pressure load of 17.7 N (1.8 kg) for 60 s horizontally to the center of capacitor side body Exception: for case size 0603 pressure load is 5N	Part should not be sheared off the pads and no body cracking post-conditioning. Electrical test not required.
Flammability	Encapsulation materials meet UL 94 V-0 with an oxygen index of 32 %	n/a

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